

Reflective Sensor

- Phototransistor output
- Focused for maximum response
- Ambient light and dust protective filter



The HOA1405 series consists of an infrared emitting diode and an NPN silicon phototransistor encased side-by-side on converging optical axes in a black thermoplastic housing. The phototransistor responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA1405 series employs an IR transmissive filter to minimize the effects of visible ambient light and to provide a smooth optical face which prevents the accumulation of airborne contaminants in the optical path. The HOA1405 series contains plastic molded components. For additional component information see SEP8505 and SPD8405.

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	2 plc decimals	$\pm 0.020(0.51)$

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HOA1405

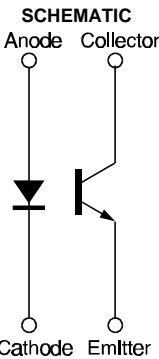
Reflective Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	V_F			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	I_R			10	μA	$V_R=3\text{ V}$
DETECTOR						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	30			V	$I_C=100\text{ }\mu\text{A}$
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	$I_E=100\text{ }\mu\text{A}$
Collector Dark Current	I_{CEO}			100	nA	$V_{CE}=10\text{ V}, I_F=0$
COUPLED CHARACTERISTICS						
On-State Collector Current	$I_{C(ON)}$				mA	$V_{CE}=5\text{ V}$ $I_F=30\text{ mA}$ (1)
HOA1405-001		0.2				
HOA1405-002		0.8				
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$				V	$I_F=30\text{ mA}$ (1)
HOA1405-001	$V_{(BR)CEO}$			0.4		$I_C=30\text{ }\mu\text{A}$
HOA1405-002				0.4		$I_C=100\text{ }\mu\text{A}$
Rise And Fall Time	t_r, t_f		15		μs	$V_{CC}=5\text{ V}, I_C=1\text{ mA}$ $R_L=1000\text{ }\Omega$

Notes
1. Test surface is a Eastman Kodak neutral white card with 90% diffuse reflectance located 0.20 in. (5.0 mm) from the front surface of the device.

ABSOLUTE MAXIMUM RATINGS	
(25°C Free-Air Temperature unless otherwise noted)	
Operating Temperature Range	-40°C to 85°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C
IR EMITTER	
Power Dissipation	70 mW (1)
Reverse Voltage	3 V
Continuous Forward Current	50 mA
DETECTOR	
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Power Dissipation	70 mW (1)

Notes
1. Derate linearly at 0.18 mW/°C above 25°C.



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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Fig. 1 IRED Forward Bias Characteristics

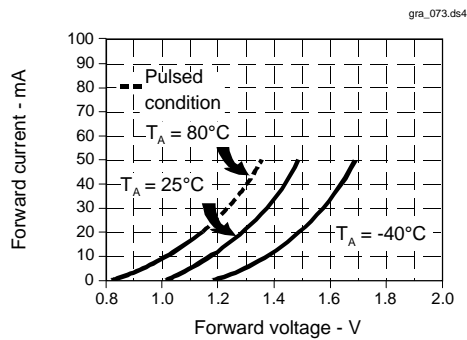


Fig. 2 Non-Saturated Switching Time vs Load Resistance

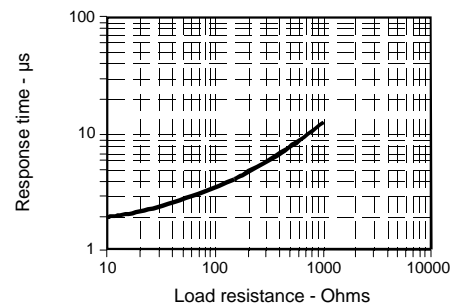


Fig. 3 Dark Current vs Temperature

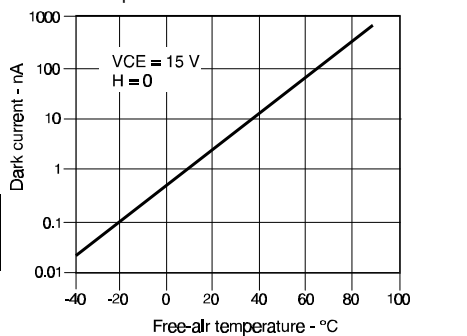


Fig. 4 Collector Current vs Ambient Temperature

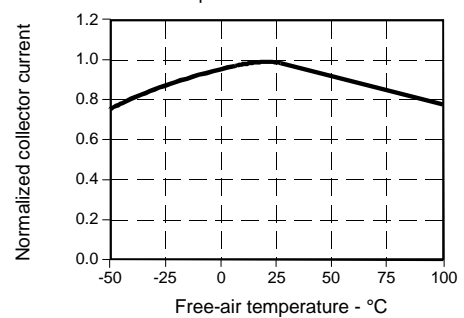


Fig. 5 Collector Current vs Distance to Reflective Surface

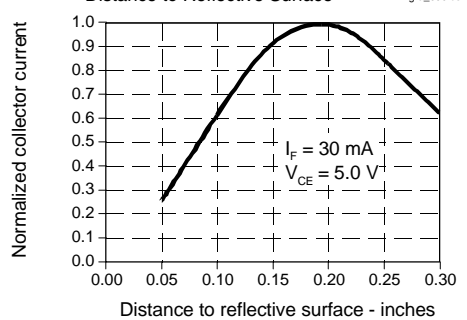
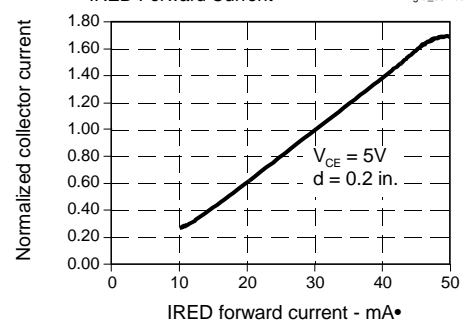


Fig. 6 Collector Current vs IRED Forward Current



All Performance Curves Show Typical Values

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